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	Substitute for fo	om 1449/	VPTO	Complete if Known		
INIEO	DRANTION	l DIC	CLOSURE	Application No.	10/765,578	
				Filing Date	January 26, 2004	
51A	IEMENIE	ot Ar	PPLICANT	First Named Inventor	Robert A. York	
				Art Unit	2811	
				Examiner Name	Not yet known	
Sheet	1	of	2	Attorney Docket Number	22994-08791	

			U.S. PAT	ENT DOCUMENTS
		Document No.		
Examiner Initials*	Cite No.1	Number – Kind Code <sup>2</sup> (if known)	Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document
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		OTHER REFERENCES - NON-PATENT LITERATURE DOCUMENTS				
Examiner Initials*	Cite No.'	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazi journat, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country when published				
hr		Acikel, Baki et al., "A New High Performance Phase Shifter using (Ba <sub>x</sub> Sr <sub>1-x</sub> TiO <sub>3</sub> Thin Films," <i>IEEE Microwave and Wireless Components Letters</i> , Vol. 12, No. 7, July 2002, pages 237-239.				
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Examiner Signature	mm	Date Considered	Sup 27	n ig
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	Substitute for	form 1449A/P	TO	Complete if Known		
INIEO	DAAATIOI	u Diec	LOSURE	Application No.	10/765,578	
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51A	IEMENI	BT API	PLICANT	First Named Inventor	Robert A. York	
				Art Unit	2811	
			•	Examiner Name	Not yet known	
Sheet	2	of	2	Attorney Docket Number	22994-08791	

<u> </u>	T 0'1-	OTHER REFERENCES – NON-PATENT LITERATURE DOCUMENTS  Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine,	г —
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